

## 8-PIN PWM SWITCHER AND LINEAR CONTROLLER IC

## FEATURES

- LDO Controller allows the use of a low cost pass transistor for the I/O supply
- 8-Pin SOIC combines switching and linear controller
- Internal pre-regulator eliminates cross talk between switching and linear regulators
- Automatic shut down of the linear regulator when connected to the Vcc2 detect pin
- On-Board MOSFET Driver
- Fastest transient response of any controller method (0 to 100% Duty Cycle in 100ns)
- 1% Internal Voltage Reference
- Internal Under-Voltage Lockout protects MOSFET during start-up

## APPLICATIONS

- Dual supply low voltage processor applications, such as: P55C™, CYRIX M2™, POWER PC™ and AMD K6™
- Simple 5V to 3.3V switcher for Pentium with AGP or Pentium II™ applications

## DESCRIPTION

The IRU3033 IC combines a switching controller and a linear regulator controller all in a compact 8-pin surface mount package, providing a total solution for dual supply processor applications such as an Intel P55C™, AMD K6™, as well as Cyrix 6X86L™ and the M2™ processors. Typically in these applications a dual supply regulator converts 5V to 3.3V for I/O supply and a jumper programmable supply of 1.25V to 3.5V for Core supply. The linear regulator controller portion in the IRU3033 is a programmable controller allowing flexibility for the I/O regulator and has a minimum of 50mA drive current capability designed to provide ample current for an external pass transistor. The IC uses an internal regulator generated from the 12V supply to power the controller as well as the 12V supply to drive the power MOSFET, allowing a low cost N-channel MOSFET switch to be used. The IC also includes an error comparator for fast transient response, a precise voltage reference for setting the output voltage as well as a direct drive of the MOSFET for the minimum part count.

## TYPICAL APPLICATION

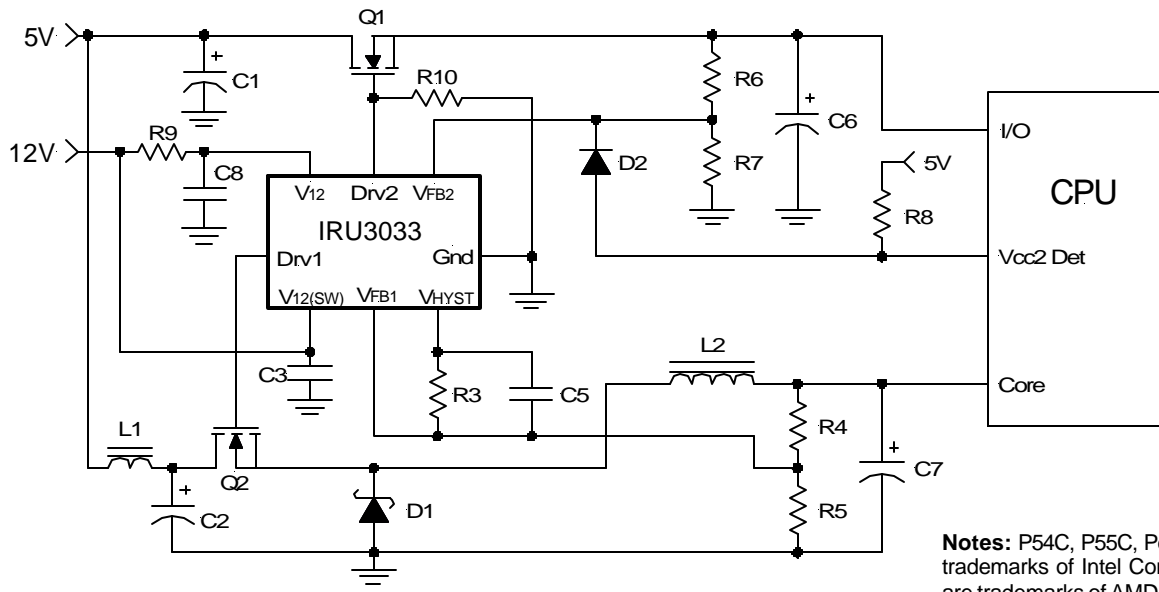


Figure 1 - Typical application of IRU3033 in a flexible mother board designed for Intel P55™, P54™, AMD K5, K6™ as well as Cyrix M1™ and M2™ applications.

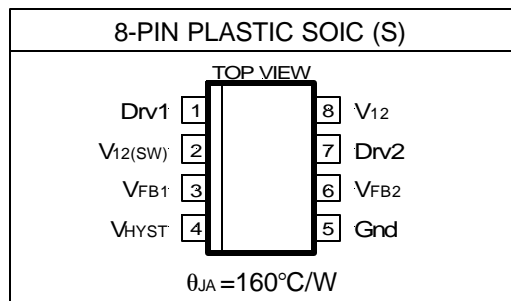
**Notes:** P54C, P55C, Pentium II are trademarks of Intel Corp. K5 & K6 are trademarks of AMD Corp. Cyrix 6X86L, M1, M2 are trademarks of Cyrix Corp. Power PC is trademark of IBM Corp.

## PACKAGE ORDER INFORMATION

|                           |                               |
|---------------------------|-------------------------------|
| <b>T<sub>A</sub> (°C)</b> | <b>8-PIN PLASTIC SOIC (S)</b> |
| 0 To 70                   | IRU3033CS                     |

**ABSOLUTE MAXIMUM RATINGS**

|  |                |
|--|----------------|
| $V_{12}, V_{12(SW)}$ Supply Voltages ..... | 20V            |
| Fb Pin Voltages .....                      | -0.3V To 5V    |
| Storage Temperature Range .....            | -65°C To 150°C |
| Operating Junction Temperature .....       | 0°C To 150°C   |

**PACKAGE INFORMATION****ELECTRICAL SPECIFICATIONS**

Unless otherwise specified, the following specification applies over  $V_{12}=V_{12(SW)}=12\text{V}$  and  $T_A=0$  to  $70^{\circ}\text{C}$ . Low duty cycle pulse testing is used which keeps junction and case temperatures equal to the ambient temperature.

| PARAMETER                           | SYM                   | TEST CONDITION  | MIN   | TYP   | MAX   | UNITS         |
|-------------------------------------|-----------------------|---|-------|-------|-------|---------------|
| <b>Linear Controller Section</b>    |                       |   |       |       |       |               |
| Fb Voltage Initial Accuracy         | $V_{FB2}$             | $T_J=25^{\circ}\text{C}$ , $\text{Drv2}=V_{FB2}$ , $C_L=100\mu\text{F}$   | 1.237 | 1.250 | 1.262 | V             |
| Fb Voltage Total Variation          |                       | $\text{Drv2}=V_{FB2}$ , $C_L=100\mu\text{F}$                              | 1.225 | 1.250 | 1.275 | V             |
| Fb Voltage Line Regulation          |                       | $10 < V_{12} < 14\text{V}$ , $\text{Drv2}=V_{FB2}$ , $C_L=100\mu\text{F}$ |       | 0.2   |       | %             |
| Fb Input Bias Current               | $I_{FB2}$             | $V_{FB2}=1.25\text{V}$  | -1    |       | +1    | $\mu\text{A}$ |
| Maximum Drive Current               | $I_{DRV(\text{max})}$ | $V_{FB2}=1\text{V}$ , $V_{FB1}=1.5\text{V}$                               |       | 50    |       | mA            |
| $V_{12}$ Supply Current             | $I_{12}$              | $V_{FB2}=1\text{V}$ , $V_{FB1}=1.5\text{V}$ , $I_{DRV2}=0$                |       | 5     |       | mA            |
| <b>Switching Controller Section</b> |                       |   |       |       |       |               |
| Fb Voltage Initial Accuracy         | $V_{FB1}$             | $T_J=25^{\circ}\text{C}$  | 1.237 | 1.250 | 1.262 | V             |
| Fb Voltage Total Variation          |                       |   | 1.225 | 1.250 | 1.275 | V             |
| Fb Voltage Line Regulation          |                       |   |       | 0.2   |       | %             |
| Fb Input Bias Current               | $I_{FB1}$             | $V_{FB1}=1.25\text{V}$  | -1    |       | +1    | $\mu\text{A}$ |
| Min On Time                         |                       | $V_{FB1}$ is sq wave with 300ns on time and $2\mu\text{s}$ off time       |       | 800   |       | ns            |
| Min Off Time                        |                       | $V_{FB1}$ is sq wave with 300ns off time and $2\mu\text{s}$ on time       |       | 800   |       | ns            |
| $V_{HYST}$ Pin Output-HI            |                       | $I_{SOURCE}=500\mu\text{A}$ , $V_{FB1}=1.5\text{V}$                       | 11    |       |       | V             |
| $V_{HYST}$ Pin Output-LO            |                       | $I_{SINK}=500\mu\text{A}$ , $V_{FB1}=1\text{V}$                           |       |       | 1     | V             |
| Supply Current                      | $I_{12(SW)}$          | $V_{FB1}=1\text{V}$ , $V_{FB2}=1.5\text{V}$                               |       | 10    |       | mA            |
| Maximum Duty Cycle                  | $D_{MAX}$             | $V_{FB1}=1\text{V}$   |       |       | 100   | %             |
| Minimum Duty Cycle                  | $D_{MIN}$             | $V_{FB1}=1.5\text{V}$   | 0     |       |       | %             |
| Gate Drive Rise/Fall Time           | $V_{GATE}$            | Load=IRL3303  |       | 70    |       | ns            |

## PIN DESCRIPTIONS

| PIN # | PIN SYMBOL          | PIN DESCRIPTION   |
|-------|---------------------|---|
| 1     | Drv1                | The PWM output of the switching controller. This pin is a totem pole drive that is connected to the gate of the power MOSFET. A resistor may be placed from this pin to the gate in order to reduce switching noise.  |
| 2     | V <sub>12(SW)</sub> | This pin supplies the voltage to the PWM drive and hysteresis circuitry and it is connected to the 12V supply. A 1 $\mu$ F, high frequency capacitor must be connected from this pin to ground to provide the peak current for charging and discharging of the MOSFET.  |
| 3     | V <sub>FB1</sub>    | A resistor divider from this pin to the output of the switching regulator and ground sets the Core supply voltage.  |
| 4     | V <sub>HYST</sub>   | A resistor and a 10pF capacitor is connected from this pin to the V <sub>FB1</sub> pin to set the output ripple voltage for the switching regulator.  |
| 5     | Gnd                 | This pin is connected to the IC substrate and must be connected to the lowest potential in the system.  |
| 6     | V <sub>FB2</sub>    | The feedback pin of the linear regulator. A resistor divider from this pin to the output of the linear regulator and ground sets the I/O supply voltage.  |
| 7     | Drv2                | The drive pin of the linear regulator. This pin controls the base of a transistor or the gate of a MOSFET acting as the series pass element for the linear regulator.   |
| 8     | V <sub>12</sub>     | This pin provides the biasing for the chip and drive for the linear regulator controller. It is connected to 12V supply. A 10 $\Omega$ resistor in series from this pin to the 12V supply and a 1 $\mu$ F, high frequency capacitor connected from this pin to ground is required to filter the switching noise of the switching regulator. |

## BLOCK DIAGRAM

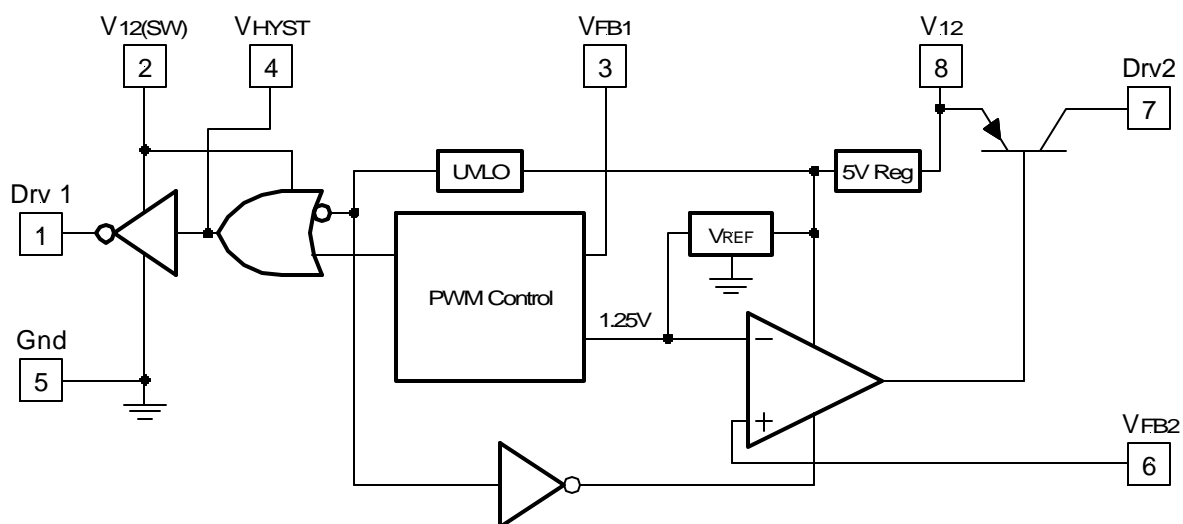


Figure 2 - Simplified block diagram of the IRU3033.



## APPLICATION PARTS LIST

### Pentium Dual Supply

| Ref Desig | Description     | Qty | Part #   | Manuf                 |
|-----------|-----------------|-----|--|-----------------------|
| U1        | LDO/Switcher IC | 1   | IRU3033CS (8-Pin SOIC)                                       | IR                    |
| Q1        | MOSFET          | 1   | MTP3055 (TO-220)   | Motorola              |
| Q2        | MOSFET          | 1   | IRL3303 (TO-220)<br>IRL3103S (TO-263) (Note 1)               | IR                    |
| D2        | Diode, GP       | 1   | 1N4148   |                       |
| D1        | Schottky Diode  | 1   | MBR1045CT (TO-220)<br>MBRB1545CT (TO-263) (Note1)            | Motorola              |
| L2        | Inductor        | 1   | Core: T50-18, L=4 $\mu$ H<br>Turns: 10T, 18 AWG              | Micro Metal<br>(core) |
| L1        | Inductor        | 1   | L=2 $\mu$ H  |                       |
| R1        | Resistor        | 1   | 22 $\Omega$ , 5%, SMT 1206 size                              |                       |
| R2        | Resistor        | 1   | 10 $\Omega$ , 5%, SMT 1206 size                              |                       |
| R3        | Resistor        | 1   | 324K $\Omega$ , 1%, SMT 0805 size                            |                       |
| R4A*      | Resistor        | 1   | 806 $\Omega$ , 1%, SMT 0805 size                             |                       |
| R4B*      | Resistor        | 1   | 90.9K $\Omega$ , 1%, SMT 0805 size                           |                       |
| R5A       | Resistor        | 1   | 1.24K $\Omega$ , 1%, SMT 0805 size                           |                       |
| R5B       | Resistor        | 1   | 2.49K $\Omega$ , 1%, SMT 0805 size                           |                       |
| R5C       | Resistor        | 1   | 4.99K $\Omega$ , 1%, SMT 0805 size                           |                       |
| R5D       | Resistor        | 1   | 1K $\Omega$ , 1%, SMT 0805 size                              |                       |
| R5E       | Resistor        | 1   | 1.30K $\Omega$ , 1%, SMT 0805 size                           |                       |
| R6        | Resistor        | 1   | 2 K $\Omega$ , 1%, SMT 0805 size                             |                       |
| R7        | Resistor        | 1   | 1.21K $\Omega$ , 1%, SMT 0805 size                           |                       |
| R8        | Resistor        | 1   | 1 K $\Omega$ , 5%, SMT 0805 size                             |                       |
| R9        | Resistor        | 1   | 10 $\Omega$ , 5%, SMT 0805 size                              |                       |
| R10       | Resistor        | 1   | 1K $\Omega$ , 5%, SMT 0805 size                              |                       |
| R11       | Resistor        | 1   | 2.4K $\Omega$ , 5%, SMT 0805 size                            |                       |
| R13       | Resistor        | 1   | 7.5K $\Omega$ , 5%, SMT 0805 size                            |                       |
| C1        | Capacitor       | 1   | 6MV1500GX, 1500 $\mu$ F, 6.3V, Elect                         |                       |
| C2        | Capacitor       | 1   | 6MV1500GX, 1500 $\mu$ F, 6.3V, Elect                         | Sanyo                 |
| C3        | Capacitor       | 1   | 1 $\mu$ F, Ceramic, SMT 0805 size                            |                       |
| C4        | Capacitor       | 1   | 470pF, Ceramic, SMT 0805 size                                | Sanyo                 |
| C5        | Capacitor       | 1   | 10pF, Ceramic, SMT 0805 size                                 | Sanyo                 |
| C6        | Capacitor       | 1   | 6MV1500GX, 1500 $\mu$ F, 6.3V, Elect                         | Sanyo                 |
| C7        | Capacitor       | 4   | 6MV1500GX, 1500 $\mu$ F, 6.3V, Elect                         | Sanyo                 |
| C8        | Capacitor       | 1   | 1 $\mu$ F, Ceramic, SMT 0805 size                            |                       |
| C9        | Capacitor       | 1   | 470p, Ceramic, SMT 0805 size                                 |                       |
| HS1       | Heat Sink       | 1   | For MOSFET, 577002   | Aavid                 |
| HS2       | Heat Sink       | 1   | For Schottky Diode , 577002                                  | Aavid                 |
| HS3       | Heat Sink       | 1   | For Q1, 507222 (I/O curren<5A)<br>576602 (I/O current< 3.5A) | Aavid                 |

\*R4 is a parallel combination of R4A and R4B.

**Note 1:** For the applications where it is desirable to eliminate the heat sink, the IRL3103S for Q2 and MBR1545CT for D2 in TO-263 packages with minimum of 1" square copper pad can be used.

## TYPICAL APPLICATION

5V to 3.3V for Pentium Application with AGP or Pentium II Application without ATX power supply Dual mode Operation between Switching or Linear mode.

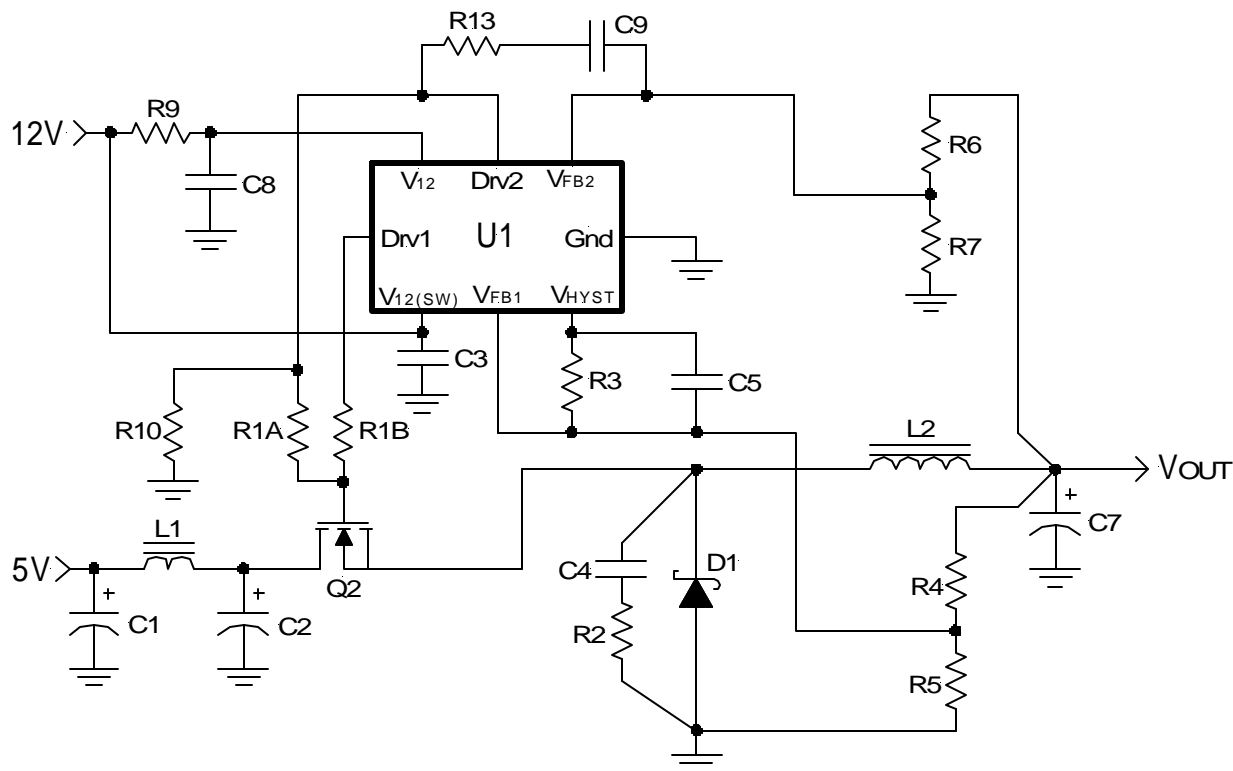


Figure 4 - This unique application of IRU3033 allows the designer to switch between Linear or Switching mode of operation using a single IC. This circuit has the flexibility to be used for low current operation in Linear mode for cost reasons and yet be able to operate in the Switching mode if the load current increases and the heat generated by the Linear operation will be an issue.

The table below describes the components that will be effected for the two modes of operation.

| Mode of Operation | L1 | L2 | D1 | C4 | C5 | R1A | R1B | R2 | R3 | R4 | R5 | R6 | R7 |
|-------------------|----|----|----|----|----|-----|-----|----|----|----|----|----|----|
| Switching         | V  | V  | V  | V  | V  | O   | V   | V  | V  | V  | V  | V  | O  |
| Linear            | S  | S  | O  | O  | O  | V   | O   | O  | O  | V  | O  | V  | V  |

V = See parts list for value      S = Short      O = Open

## APPLICATION PARTS LIST

5V to 3.3V for Pentium Application with AGP or Pentium II Application without ATX power supply Dual mode Operation between Switching or Linear mode.

| Ref Desig | Description     | Qty | Part #   | Manuf                 |
|-----------|-----------------|-----|--|-----------------------|
| U1        | LDO/Switcher IC | 1   | IRU3033CS (8-Pin SOIC)   | IR                    |
| Q2        | MOSFET          | 1   | IRL3303 (TO-220)<br>IRL3103S (TO-263) (Note 1)   | IR                    |
| D1        | Schottky Diode  | 1   | MBR1045CT (TO-220)<br>MBRB1545CT (TO-263) (Note1)  | Motorola              |
| L2        | Inductor        | 1   | Core: T50-18, L=4 $\mu$ H<br>Turns: 10T, 18 AWG  | Micro Metal<br>(core) |
| L1        | Inductor        | 1   | L=2 $\mu$ H  |                       |
| R1A       | Resistor        | 1   | 2.4K $\Omega$ , 5%, SMT 1206 size  |                       |
| R1B       | Resistor        | 1   | 22 $\Omega$ , 5%, SMT 1206 size  |                       |
| R2        | Resistor        | 1   | 10 $\Omega$ , 5%, SMT 1206 size  |                       |
| R3        | Resistor        | 1   | 249K $\Omega$ , 1%, SMT 0805 size  |                       |
| R4        | Resistor        | 1   | 1K $\Omega$ , 1%, SMT 0805 size  |                       |
| R5        | Resistor        | 1   | 576 $\Omega$ , 1%, SMT 0805 size   |                       |
| R6        | Resistor        | 1   | 180 $\Omega$ , 1%, SMT 0805 size   |                       |
| R7        | Resistor        | 1   | 100 $\Omega$ , 1%, SMT 0805 size   |                       |
| R9        | Resistor        | 1   | 10 $\Omega$ , 5%, SMT 1206 size  |                       |
| R10       | Resistor        | 1   | 1K $\Omega$ , 5%, SMT 1206 size  |                       |
| R13       | Resistor        | 1   | 7.5K $\Omega$ , 5%, SMT 1206 size  |                       |
| C1, 2     | Capacitor       | 2   | 6MV1500GX, 1500 $\mu$ F, 6.3V, Elect   | Sanyo                 |
| C3        | Capacitor       | 1   | 1 $\mu$ F, Ceramic, SMT 0805 size  |                       |
| C4        | Capacitor       | 1   | 470pF, Ceramic, SMT 0805 size  | Sanyo                 |
| C5        | Capacitor       | 1   | 10pF, Ceramic, SMT 0805 size   | Sanyo                 |
| C7        | Capacitor       | 1   | 6MV1500GX, 1500 $\mu$ F, 6.3V, Elect   | Sanyo                 |
| C8        | Capacitor       | 1   | 1 $\mu$ F, Ceramic, SMT 0805 size  |                       |
| C9        | Capacitor       | 1   | 470pF, Ceramic, SMT 0805 size  |                       |
| HS1       | Heat Sink       | 1   | For MOSFET in Switching mode, 577002<br>For MOSFET in Linear mode:<br>507222 (3.3V current<5A),<br>576602 (3.3V current< 3.5A) | Aavid                 |
| HS2       | Heat Sink       | 1   | For Schottky Diode, 577002   | Aavid                 |

**Note 1:** For the applications where it is desirable to eliminate the heat sink, the IRL3103S for Q2 and MBR1545CT for D2 in TO-263 packages with minimum of 1" square copper pad can be used.

## TYPICAL APPLICATION

**5V to 3.3V for Pentium application with AGP or Pentium II application without ATX power supply switching mode operation.**

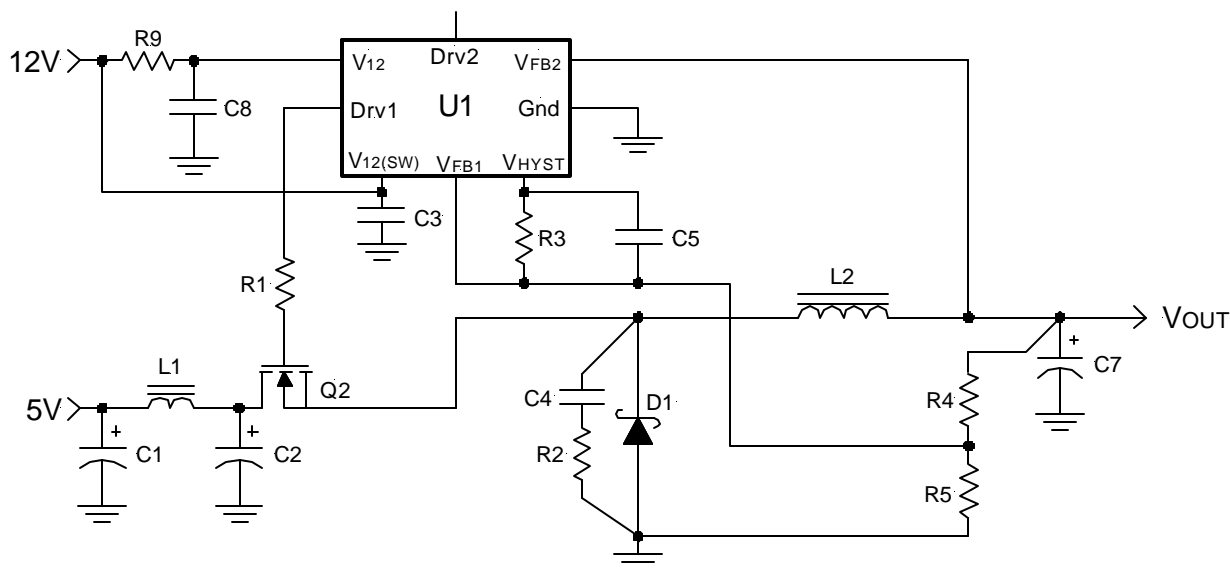


Figure 5 - The circuit in figure 4 is the application of the IRU3033 in a switching mode only. This circuit can be used to generate a low cost 5V to 3.3V for either Pentium application with AGP socket or in Pentium II applications where it is desirable to generate an accurate on board 3.3V supply.

| Ref Desig | Description     | Qty | Part #   | Manuf                 |
|-----------|-----------------|-----|--|-----------------------|
| U1        | LDO/Switcher IC | 1   | IRU3033CS (8-Pin SOIC)                             | IR                    |
| Q2        | MOSFET          | 1   | IRL3303 (TO-220)<br>IRL3103S (TO-263) (Note 1)     | IR                    |
| D1        | Schottky Diode  | 1   | MBR1045CT (TO-220)<br>MBRB1545CT (TO-263) (Note 1) | Motorola              |
| L2        | Inductor        | 1   | Core: T50-18, L=4μH<br>Turns: 10T, 18 AWG          | Micro Metal<br>(core) |
| L1        | Inductor        | 1   | L=2μH  |                       |
| R1        | Resistor        | 1   | 22Ω, 5%, SMT 1206 size                             |                       |
| R9        | Resistor        | 1   | 10Ω, 5%, SMT 0805 size                             |                       |
| R2        | Resistor        | 1   | 10Ω, 5%, SMT 1206 size                             |                       |
| R3        | Resistor        | 1   | 249KΩ, 1%, SMT 0805 size                           |                       |
| R4        | Resistor        | 1   | 1KΩ, 1%, SMT 0805 size                             |                       |
| R5        | Resistor        | 1   | 576Ω, 1%, SMT 0805 size                            |                       |
| C1, 2     | Capacitor       | 2   | 6MV1500GX, 1500μF, 6.3V, Elect                     | Sanyo                 |
| C3        | Capacitor       | 1   | 1μF, Ceramic, SMT 0805 size                        |                       |
| C4        | Capacitor       | 1   | 470pF, Ceramic, SMT 0805 size                      | Sanyo                 |
| C5        | Capacitor       | 1   | 10pF, Ceramic, SMT 0805 size                       | Sanyo                 |
| C7        | Capacitor       | 1   | 6MV1500GX, 1500μF, 6.3V, Elect                     | Sanyo                 |
| C8        | Capacitor       | 1   | 1μF, Ceramic, SMT 0805 size                        |                       |
| HS1       | Heat Sink       | 1   | For MOSFET, 577002                                 | Aavid                 |
| HS2       | Heat Sink       | 1   | For Schottky Diode, 577002                         | Aavid                 |

**Note 1:** For the applications where it is desirable to eliminate the heat sink, the IRL3103S for Q2 and MBR1545CT for D2 in TO-263 packages with minimum of 1" square copper pad can be used.



## APPLICATION INFORMATION

### Introduction

The IRU3033 device is an application specific product designed to provide an on board dual supply for the new generation of microprocessors requiring separate Core and I/O supplies. One of the processors fitting this requirement is the new Intel P55C™ multimedia microprocessor. Intel specifies a Core voltage of 2.8V nominal ( $\pm 100\text{mV}$  max) with maximum Core supply current of 6A while the I/O supply is set for 3.3V with a maximum I/O current of 0.65A. However, in most applications the I/O regulator also provides the voltage for other IC functions such as the chip set, cache, etc. Typically a low cost solution such as a Low Dropout (LDO) Linear Regulator is selected to provide the I/O supply with the maximum designed current of 3A, keeping the power dissipation and the heat sink to a reasonable size. The Core supply regulator, however, if also selected to be a linear regulator, will be dissipating a maximum of 12.6W  $[(5\text{V}-2.8\text{V})\times 5.7\text{A}]$  of power, which requires a substantial amount of heat sinking and perhaps forced air cooling in order to keep it operational. Some manufacturers suggest using two regulators to current share and therefore distribute the power dissipation equally between the regulators. The problem is that, in order to equally current share you need to sense both currents and force the slave regulator to match the master regulator. This can be done, but at the cost of the circuit complexity and much higher system cost and the total power dissipation is still the same. In fact, if the task is to design a flexible motherboard to accommodate the Cyrix 6X86L or their future MMX processors, then the power dissipation could easily reach 20W or more. At this power dissipation level the choice for a switching regulator approach becomes evident. However, the main reason that designers have always shied away from the switching regulators is their higher price tag and more complex circuit design that is associated with this kind of technique.

The IRU3033 device is designed to take advantage of the high efficiency of the switching regulator technique for the Core supply while maintaining the low cost LDO regulator for the I/O supply by offering both control functions in a single 8-pin surface mount package. In fact, as the typical application circuit shows, one can design a complete flexible motherboard using the IRU3033 and a few external components yielding a very low component count switching regulator and with an addition of a low cost pass transistor for the I/O supply provide a complete dual supply power solution.

### LDO Section

The output voltage of the LDO regulator is externally programmable via 2 external resistors from 1.25V to 5V. The internal voltage reference of the LDO regulator is set to 1.25V and the output of the regulator can be programmed using the following formula:

$$V_{\text{OUT}} = (1 + R1/R2) \times V_{\text{REF}}$$

Where:

$V_{\text{REF}} = 1.25\text{V}$  Typical

R1 = Resistor connected from  $V_{\text{OUT}}$  to the  $V_{\text{FB2}}$  pin of IRU3033.

R2 = Resistor connected from  $V_{\text{FB2}}$  pin to Gnd.

The IRU3033 requires the use of an output capacitor as part of the frequency compensation in order to be stable. Typical designs for the microprocessor applications use standard electrolytic capacitors with typical ESR in the range of 50 to 100m $\Omega$  and an output capacitance of 500 to 1000 $\mu\text{F}$ . Fortunately as the capacitance increases, the ESR decreases resulting in a fixed RC time constant. The IRU3033 takes advantage of this phenomena in making the overall regulator loop stable. For most applications a minimum of 100 $\mu\text{F}$  aluminum electrolytic capacitor such as Sanyo, MVGX series, Panasonic FA series or Nichicon PL series insures both stability and good transient response.

An external filtering is suggested as shown in the application circuit that reduces the switching ripple that might show in the output of the LDO regulator.

### Switching Controller Operation

The operation of the switching controller is as follows:

After the power is applied, the output drive (Drv1) goes to 100% duty cycle and the current in the inductor charges the output capacitor causing the output voltage to increase. When output reaches a pre-programmed set point the feedback pin ( $V_{\text{FB1}}$ ) exceeds 1.25V causing the output drive to switch low and the  $V_{\text{HYST}}$  pin to switch high which jumps the feedback pin higher than 1.25V resulting in a fixed output ripple which is given by the following equation:

$$\Delta V_o = (R_t/R_b) \times 11$$

Where:

$R_t$  = Top resistor of the output divider, resistor connected from  $V_{\text{OUT}}$  to the  $V_{\text{FB1}}$  pin of IRU3033.

$R_b$  = Bottom resistor of the divider, resistor connected from  $V_{\text{FB1}}$  pin to  $V_{\text{HYST}}$  pin.

For example, if  $R_t=1K$  and  $R_b=422K$ , then the output ripple is:

$$\Delta V_o = (1/422) \times 11 = 26mV$$

The advantage of fixed output ripple is that when the output voltage changes from 2V to 3.5V, the ripple voltage remains the same which is important in meeting the Intel maximum tolerance specification.

## Switcher Output Voltage Setting

The output voltage of the switcher can be set using the following equations:

Assuming,  $V_o=3.38V$  and the selected output ripple is  $\approx 1.3\%(44mV)$  of the output voltage, a set of equations are derived that selects the resistor divider and the hysteresis resistor.

Assuming,  $R_t=1K\Omega$ , 1%:

$$R_H = (11 \times R_t) / \Delta V$$

Where:

$R_t$  = Top resistor of the resistor divider.

$R_H$  = Hysteresis resistor connected between pins 3 and 4 of the IRU3033.

$\Delta V_o$  = Selected output ripple (typically 1% to 2% of output voltage).

Assuming,  $\Delta V_o=44mV$ :

$$R_H = (11 \times 1000) / 0.044 = 250K\Omega$$

Select  $R_H = 249K\Omega$ , 1%

The bottom resistor of the divider is then calculated using the following equations:

$$R_B = R_t / X$$

Where:

$R_B$  = Bottom resistor of the divider

$V_{REF} = 1.25V$  typical

$$X = [(V_o + \frac{\Delta V_o}{2}) / V_{REF}] - 1$$

$$X = [(3.38 + \frac{0.044}{2}) / 1.25] - 1 = 1.72$$

$$R_B = 1000 / 1.72 = 580\Omega$$

Select  $R_B = 576\Omega$ , 1%

## Frequency Calculation

The IRU3033 frequency of operation is calculated using the following formula:

$$F_s = [(V_o \times (1 - D) \times ESR)] / (L \times \Delta V_o) \quad (MHz)$$

Where:

$V_o$  = Output voltage (V)

$D$  = Duty cycle

$ESR$  = Output capacitor ESR (V)

$L$  = Output inductance ( $\mu H$ )

$\Delta V_o$  = Output ripple voltage (V)

For our example:

$$D \approx (V_o + V_f) / V_{IN}$$

Where:

$V_f$  = Forward voltage drop of the Schottky diode.

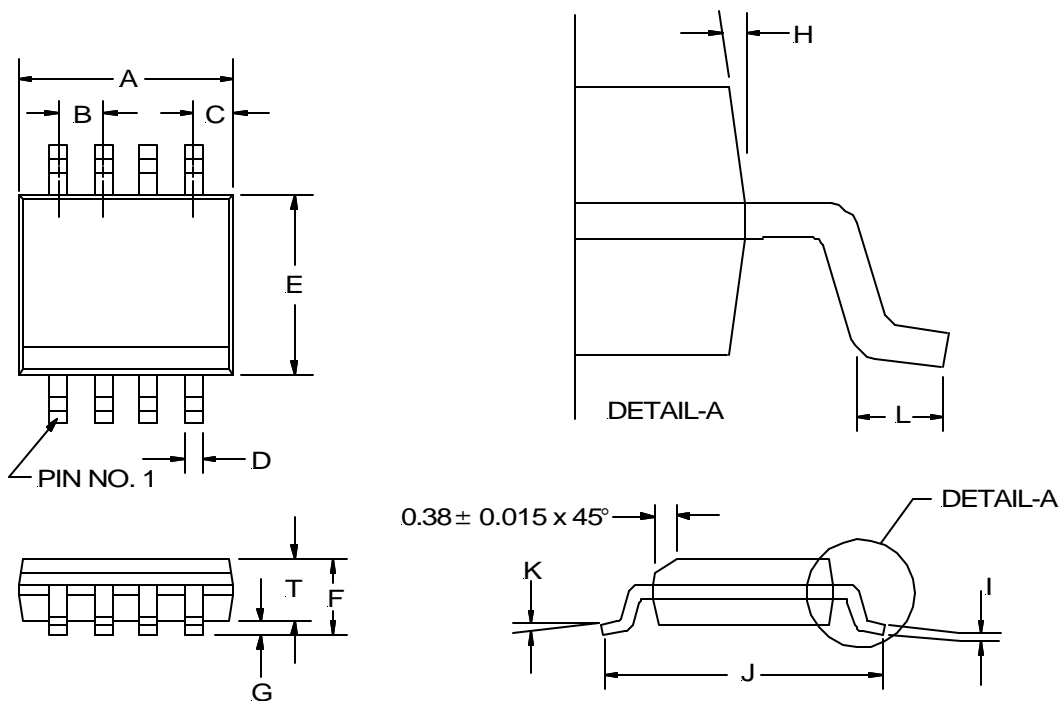
$$D = (3.38 + 0.5) / 5 = 0.78$$

The  $ESR=18m\Omega$  for 2 of the Sanyo 1500 $\mu F$ , 6MV1500GX caps. If  $L=3.5\mu H$  then,  $F_s$  is calculated as follows:

$$F_s = \frac{[(3.38 \times (1 - 0.78) \times 0.018)]}{(3.5 \times 0.044)} = 0.087MHz$$

$$F_s = 87KHz$$

**(S) SOIC Package**  
**8-Pin Surface Mount, Narrow Body**



| 8-PIN  |          |      |
|--------|----------|------|
| SYMBOL | MIN      | MAX  |
| A      | 4.80     | 4.98 |
| B      | 1.27 BSC |      |
| C      | 0.53 REF |      |
| D      | 0.36     | 0.46 |
| E      | 3.81     | 3.99 |
| F      | 1.52     | 1.72 |
| G      | 0.10     | 0.25 |
| H      | 7° BSC   |      |
| I      | 0.19     | 0.25 |
| J      | 5.80     | 6.20 |
| K      | 0°       | 8°   |
| L      | 0.41     | 1.27 |
| T      | 1.37     | 1.57 |

NOTE: ALL MEASUREMENTS ARE IN MILLIMETERS.

**PACKAGE SHIPMENT METHOD**

| PKG<br>DESIG | PACKAGE<br>DESCRIPTION | PIN<br>COUNT | PARTS<br>PER TUBE | PARTS<br>PER REEL | T & R<br>Orientation |
|--------------|------------------------|--------------|-------------------|-------------------|----------------------|
| S            | SOIC, Narrow Body      | 8            | 95                | 2500              | Fig A                |

